# Hyperfast Diode

50 A, 600 V

# **RHRG5060**

#### Description

The RHRG5060 is a hyperfast diode with soft recovery characteristics. It has the half recovery time of ultrafast diodes and is silicon nitride passivated ionimplanted epitaxial planar construction. These devices are intended to be used as freewheeling/ clamping diodes and diodes in a variety of switching power supplies and other power switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

#### Features

- Hyperfast Recovery ( $t_{rr} = 50 \text{ ns} (@ I_F = 50 \text{ A})$ )
- Max Forward Voltage( $V_F = 2.1 \text{ V}$  (@  $T_C = 25 \text{ °C}$ )
- 600 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- This Device is Pb-Free and is RoHS Compliant

#### Applications

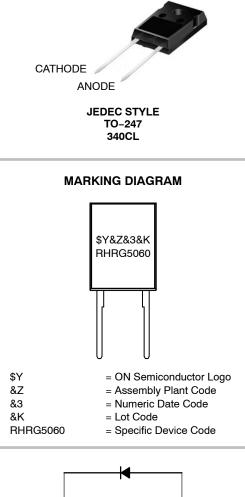
- Switching Power Supplies
- Power Switching Circuits
- General Purpose

#### ABSOLUTE MAXIMUM RATINGS (T<sub>C</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>	600	V
Working Peak Reverse Voltage	V <sub>RWM</sub>	600	V
DC Blocking Voltage	V <sub>R</sub>	600	V
Average Rectified Forward Current (T <sub>C</sub> = 93 $^{\circ}$ C)	I <sub>F(AV)</sub>	50	A
Repetitive Peak Surge Current (Square Wave, 20 kHz)	I <sub>FRM</sub>	100	A
Nonrepetitive Peak Surge Current (Halfwave 1 Phase, 60 Hz)	I <sub>FSM</sub>	500	A
Maximum Power Dissipation	PD	150	W
Avalanche Energy (See Figure 10 and Figure 11)	E <sub>AVL</sub>	40	mJ
Operating and Storage Temperature	T <sub>STG,</sub> T <sub>J</sub>	–65 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.





#### ORDERING INFORMATION

1. Cathode

See detailed ordering and shipping information on page 2 of this data sheet.

2. Anode

# **RHRG5060**

#### PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Package	Brand
RHRG5060	TO-247-2L	RHRG5060

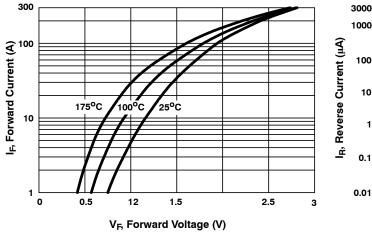
#### ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V <sub>F</sub>	/ <sub>F</sub> Instantaneous Forward Voltage (Pulse Width = 300 μs, Duty Cycle = 2%)	I <sub>F</sub> = 50 A			2.1	V
		I <sub>F</sub> = 50 A, T <sub>C</sub> = 150°C			1.7	V
I <sub>R</sub>	Instantaneous Reverse Current	V <sub>R</sub> = 600 V			250	μA
		V <sub>R</sub> = 600 V T <sub>C</sub> = 150°C			1.5	mA
t <sub>rr</sub>	Reverse Recovery Time (See Figure 9 ) Summation of $t_a$ + $t_b$	I <sub>F</sub> = 1 A, dI <sub>F</sub> /dt = 100 A/μs			45	ns
		I <sub>F</sub> = 50 A, dI <sub>F</sub> /dt = 100 A/μs			50	ns
t <sub>a</sub>	Time to Reach Peak Reverse Current (See Figure 9)	I <sub>F</sub> = 50 A, dI <sub>F</sub> /dt = 100 A/μs		25		ns
t <sub>b</sub>	Time from Peak $I_{RM}$ to Projected Zero Crossing of $I_{RM}$ Based on a Straight Line from Peak $I_{RM}$ Through 25% of $I_{RM}$ (See Figure 9)	I <sub>F</sub> = 50 A, dI <sub>F</sub> /dt = 100 A/μs		20		ns
Q <sub>rr</sub>	Reverse Recovery Charge	I <sub>F</sub> = 50 A, dI <sub>F</sub> /dt = 100 A/μs		65		nC
CJ	Junction Capacitance	V <sub>R</sub> = 10 V, I <sub>F</sub> = 0 A		140		pF
$R_{\theta JC}$	Thermal Resistance Junction to Case				1.0	°C/W

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## **RHRG5060**

# **TYPICAL PERFORMANCE CURVES**



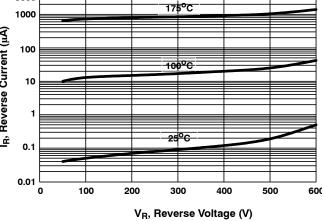


Figure 1. Forward Current vs. Forward Voltage



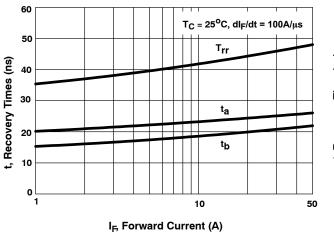
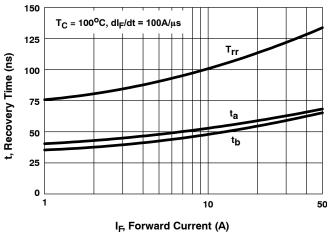
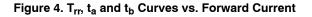
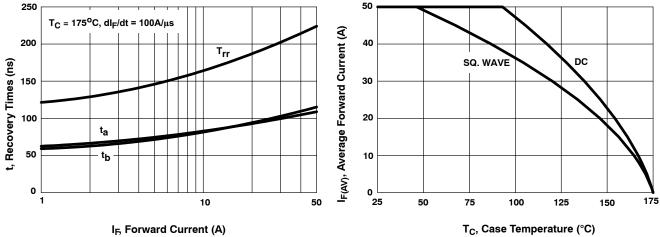


Figure 3. T<sub>rr</sub>, t<sub>a</sub> and t<sub>b</sub> Curves vs. Forward Current







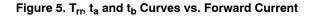
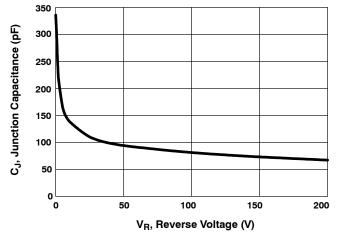


Figure 6. Current Derating Curve

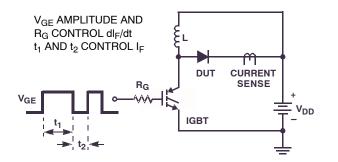
## **RHRG5060**

#### TYPICAL PERFORMANCE CURVES (continued)





#### **TEST CIRCUITS AND WAVEFORMS**





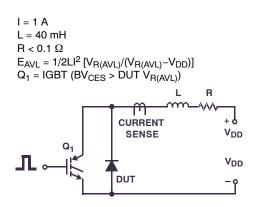


Figure 10. Avalanche Energy Test Circuit

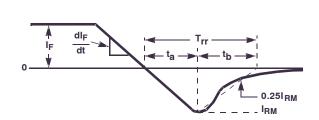


Figure 9. T<sub>rr</sub> Waveforms and Definitions

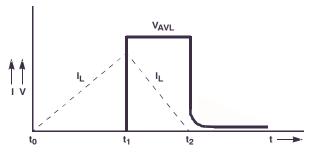


Figure 11. Avalanche Current and Voltage Waveforms

F

А

E2

E2/2 (2X)

TO-247-2LD CASE 340CL **ISSUE A** DATE 03 DEC 2019 Α *σ***P** — A2 D В

A1

С

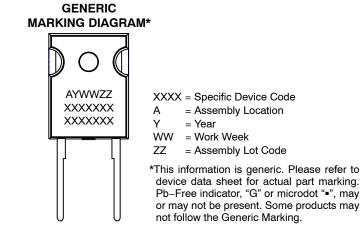
L1 (2X) b2 – (2X) b  $\oplus$  0.25 (M) B A(M)е

2

Q

NOTES: UNLESS OTHERWISE SPECIFIED.

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/─ ØP1 \_\_

ΨΓ	$\backslash$	D2
S		D1

**ON Semiconductor** 

	MILLIMETERS		
DIM	MIN	NOM	MAX
Α	4.58	4.70	4.82
A1	2.29	2.40	2.66
A2	1.30	1.50	1.70
b	1.17	1.26	1.35
b2	1.53	1.65	1.77
С	0.51	0.61	0.71
D	20.32	20.57	20.82
D1	16.37	16.57	16.77
D2	0.51	0.93	1.35
Е	15.37	15.62	15.87
E1	12.81	~	~
E2	4.96	5.08	5.20
е	~	11.12	~
L	15.75	16.00	16.25
L1	3.69	3.81	3.93
ØР	3.51	3.58	3.65
Ø <b>P</b> 1	6.61	6.73	6.85
Q	5.34	5.46	5.58
S	5.34	5.46	5.58

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